DISCRETE SEMICONDUCTORS

DATA SHEET

PEMH1; PUMH1 NPN/NPN resistor-equipped transistors; R1 = 22 kΩ, R2 = 22 kΩ

Product specification Supersedes data of 2001 Oct 22 2003 Oct 08





NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

FEATURES

- Built-in bias resistors
- · Simplified circuit design
- Reduction of component count
- · Reduced pick and place costs.

APPLICATIONS

- · Low current peripheral driver
- Replacement of general purpose transistors in digital applications
- . Control of IC inputs.

QUICK REFERENCE DATA

| SYMBOL | PARAMETER | TYP. | MAX. | UNIT |
|------------------|---------------------------|------|------|------|
| V _{CEO} | collector-emitter voltage | _ | 50 | V |
| Io | output current (DC) | _ | 100 | mA |
| TR1 | NPN | _ | _ | _ |
| TR2 | NPN | _ | _ | _ |
| R1 | bias resistor | 22 | _ | kΩ |
| R2 | bias resistor | 22 | _ | kΩ |

DESCRIPTION

NPN/NPN resistor-equipped transistors (see "Simplified outline, symbol and pinning" for package details).

PRODUCT OVERVIEW

| TYPE | PACKAGE | | MARKING CODE | NPN/PNP | PNP/PNP |
|--------|---------|-------|--------------------|------------|------------|
| NUMBER | PHILIPS | EIAJ | WARKING CODE | COMPLEMENT | COMPLEMENT |
| PEMH1 | SOT666 | | H2 | PEMD2 | PEMB1 |
| PUMH1 | SOT363 | SC-88 | H*2 ⁽¹⁾ | PUMD2 | PUMB1 |

Note

- 1. * = p: Made in Hong Kong.
 - * = t: Made in Malaysia.
 - * = W: Made in China.

SIMPLIFIED OUTLINE, SYMBOL AND PINNING

| TYPE NUMBER | CIMPLIFIED OLITHINE AND CVMDOL | | PINNING | | |
|-------------|--------------------------------|-----|---------------|--|--|
| TYPE NUMBER | SIMPLIFIED OUTLINE AND SYMBOL | PIN | DESCRIPTION | | |
| PEMH1 | 6 5 4 | 1 | emitter TR1 | | |
| PUMH1 | | 2 | base TR1 | | |
| | R1 R2 | 3 | collector TR2 | | |
| | TR2 | | emitter TR2 | | |
| | TR1 R2 R1 | 5 | base TR2 | | |
| | | 6 | collector TR1 | | |
| | 1 2 3 | | | | |
| | Top view MHC650 | | | | |
| | MHC650 | | | | |
| | | | | | |

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

ORDERING INFORMATION

| TYPE NUMBER | | PACKAGE | | | | |
|--------------|------|--|---------|--|--|--|
| I TPE NUMBER | NAME | DESCRIPTION | VERSION | | | |
| PEMH1 | _ | plastic surface mounted package; 6 leads | SOT666 | | | |
| PUMH1 | _ | plastic surface mounted package; 6 leads | SOT363 | | | |

LIMITING VALUES

In accordance with the Absolute Maximum Rating System (IEC 60134).

| SYMBOL | PARAMETER | CONDITIONS | MIN. | MAX. | UNIT |
|------------------|-------------------------------|--------------------------|------|------|------|
| V _{CBO} | collector-base voltage | open emitter | _ | 50 | V |
| V _{CEO} | collector-emitter voltage | open base | _ | 50 | V |
| V _{EBO} | emitter-base voltage | open collector | _ | 10 | V |
| VI | input voltage | | | | |
| | positive | | _ | +40 | V |
| | negative | | _ | -10 | V |
| Io | output current (DC) | | _ | 100 | mA |
| I _{CM} | peak collector current | | _ | 100 | mA |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | |
| | SOT363 | note 1 | _ | 200 | mW |
| | SOT666 | notes 1 and 2 | _ | 200 | mW |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | | _ | 150 | °C |
| T _{amb} | operating ambient temperature | | -65 | +150 | °C |
| Per device | | | | • | • |
| P _{tot} | total power dissipation | T _{amb} ≤ 25 °C | | | |
| | SOT363 | note 1 | _ | 300 | mW |
| | SOT666 | notes 1 and 2 | _ | 300 | mW |

Notes

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

THERMAL CHARACTERISTICS

| SYMBOL | PARAMETER | CONDITIONS | VALUE | UNIT |
|---------------------|---|--------------------------|-------|------|
| Per transist | or | | • | |
| R _{th j-a} | thermal resistance from junction to ambient | T _{amb} ≤ 25 °C | | |
| | SOT363 | note 1 | 625 | K/W |
| | SOT666 | notes 1 and 2 | 625 | K/W |
| Per device | | | | |
| R _{th j-a} | thermal resistance from junction to ambient | T _{amb} ≤ 25 °C | | |
| | SOT363 | note 1 | 416 | K/W |
| | SOT666 | notes 1 and 2 | 416 | K/W |

Notes

- 1. Device mounted on an FR4 printed-circuit board, single-sided copper, standard footprint.
- 2. Reflow soldering is the only recommended soldering method.

CHARACTERISTICS

 T_{amb} = 25 °C unless otherwise specified.

| SYMBOL | PARAMETER | CONDITIONS | MIN. | TYP. | MAX. | UNIT |
|--------------------|--------------------------------------|---|------|------|------|------|
| I _{CBO} | collector-base cut-off current | V _{CB} = 50 V; I _E = 0 | _ | _ | 100 | nA |
| I _{CEO} | collector-emitter cut-off current | $V_{CE} = 30 \text{ V}; I_{B} = 0$ | _ | _ | 1 | μΑ |
| | | V _{CE} = 30 V; I _B = 0; T _j = 150 °C | _ | _ | 50 | μΑ |
| I _{EBO} | emitter-base cut-off current | V _{EB} = 5 V; I _C = 0 | _ | _ | 180 | μΑ |
| h _{FE} | DC current gain | V _{CE} = 5 V; I _C = 5 mA | 60 | _ | _ | |
| V _{CEsat} | collector-emitter saturation voltage | $I_C = 10 \text{ mA}; I_B = 0.5 \text{ mA}$ | _ | _ | 150 | mV |
| $V_{i(off)}$ | input-off voltage | $I_C = 100 \mu\text{A}; V_{CE} = 5 \text{V}$ | _ | 1.1 | 0.8 | V |
| V _{i(on)} | input-on voltage | $I_C = 5 \text{ mA}; V_{CE} = 0.3 \text{ V}$ | 2.5 | 1.7 | _ | V |
| R1 | input resistor | | 15.4 | 22 | 28.6 | kΩ |
| R2 R1 | resistor ratio | | 0.8 | 1 | 1.2 | |
| C _c | collector capacitance | $I_E = i_e = 0$; $V_{CB} = 10 \text{ V}$; $f = 1 \text{ MHz}$ | | | 2.5 | pF |

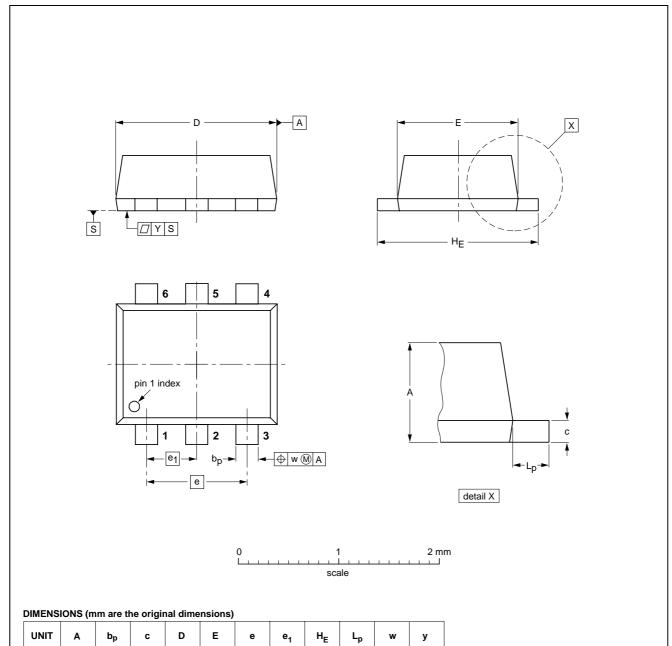
NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

PACKAGE OUTLINES

Plastic surface mounted package; 6 leads

SOT666



| OUTLINE | REFERENCES | | | EUROPEAN | ISSUE DATE | |
|---------|------------|-------|------|----------|------------|----------------------------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT666 | | | | | | -01-01-04 01-08-27 |

0.1

0.5

2003 Oct 08 5

0.6

0.27

0.17

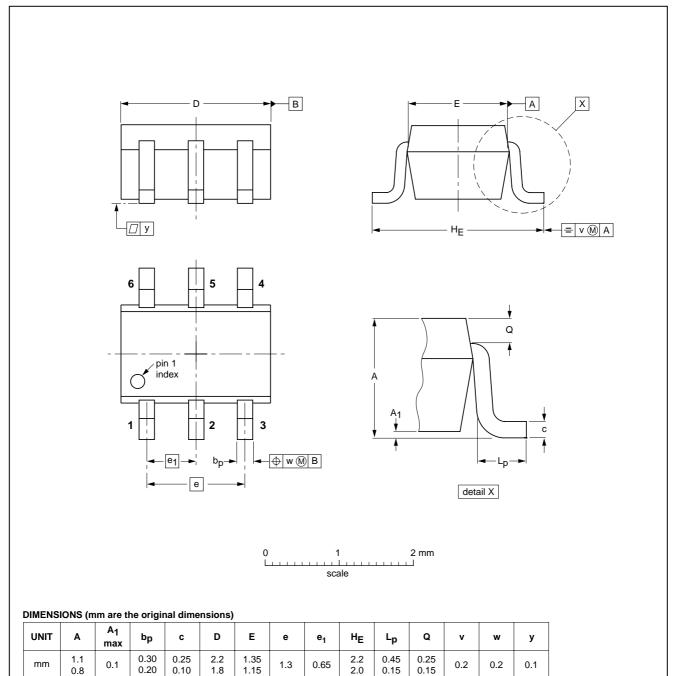
0.18

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

Plastic surface mounted package; 6 leads

SOT363



| OUTLINE | | REFERENCES | | | | ISSUE DATE |
|---------|-----|------------|-------|--|------------|------------|
| VERSION | IEC | JEDEC | EIAJ | | PROJECTION | ISSUE DATE |
| SOT363 | | | SC-88 | | | 97-02-28 |

NPN/NPN resistor-equipped transistors; R1 = 22 k Ω , R2 = 22 k Ω

PEMH1; PUMH1

DATA SHEET STATUS

| LEVEL | DATA SHEET STATUS ⁽¹⁾ | PRODUCT STATUS(2)(3) | DEFINITION |
|-------|-------------------------------------|-------------------------|--|
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Notes

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Limiting values definition — Limiting values given are in accordance with the Absolute Maximum Rating System (IEC 60134). Stress above one or more of the limiting values may cause permanent damage to the device. These are stress ratings only and operation of the device at these or at any other conditions above those given in the Characteristics sections of the specification is not implied. Exposure to limiting values for extended periods may affect device reliability.

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